TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7WZ74FU,TC7WZ74FK

### D-Type Flip Flop with Preset and Clear

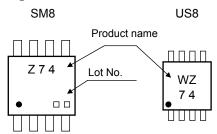
### **Features**

- High output current: ±24 mA (min) at V<sub>CC</sub> = 3 V
- Super high speed operation: t<sub>pd</sub> = 2.8 ns (typ.)

at  $V_{CC} = 5 \text{ V}, 50 \text{ pF}$ 

- Operating voltage range: V<sub>CC (opr)</sub> = 1.65 to 5.5 V
- 5.5-V Tolerant inputs
- 5.5-V Power down protection outputs
- Matches the performance of TC74LCX series when operated at 3.3- V VCC

### Marking



### Absolute Maximum Ratings (Ta = 25°C)

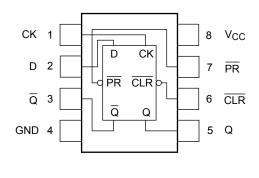
| Characteristics                    | Symbol           | Rating                                | Unit     |  |
|------------------------------------|------------------|---------------------------------------|----------|--|
| Supply voltage range               | V <sub>CC</sub>  | -0.5 to 6                             | V        |  |
| DC input voltage                   | V <sub>IN</sub>  | -0.5 to 6                             | <b>V</b> |  |
| DC output voltage                  | Vour             | -0.5 to 6 (Note 1)                    | <b>V</b> |  |
| DC output voltage                  | Vout             | -0.5 to V <sub>CC</sub> +0.5 (Note 2) | v        |  |
| Input diode current                | I <sub>IK</sub>  | -20                                   | mA       |  |
| Output diode current               | lok              | -20 (Note 3)                          | mA       |  |
| DC output current                  | lout             | ±50                                   | mA       |  |
| DC V <sub>CC</sub> /ground current | Icc              | ±50                                   | mA       |  |
| Power dissipation                  | PD               | 300 (SM8)<br>200 (US8)                | mW       |  |
| Storage temperature                | T <sub>stg</sub> | -65 to 150                            | °C       |  |
| Lead temperature (10s)             | TL               | 260                                   | °C       |  |

# TC7WZ74FU SSOP8-P-0.65 (SM8) TC7WZ74FK SSOP8-P-0.50A (US8)

Weight

SSOP8-P-0.65 : 0.02 g (typ.) SSOP8-P-0.50A : 0.01 g (typ.)

### Pin Assignment (top view)



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{CC} = 0 V$ 

Note 2: High or Low State. Do not exceed IOUT of absolute maximum ratings.

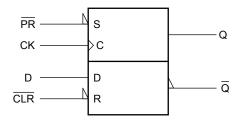
Note 3: V<sub>OUT</sub> < GND

### **Truth Table**

| Inputs |    |   | Out     | puts | Function |           |
|--------|----|---|---------|------|----------|-----------|
| CLR    | PR | D | CK      | Q    | Q        | Function  |
| L      | Н  | Х | Х       | L    | Н        | Clear     |
| Н      | L  | Χ | Х       | Н    | L        | Preset    |
| L      | L  | Χ | Х       | Н    | Н        | _         |
| Н      | Н  | L |         | L    | Н        | _         |
| Н      | Н  | Н | <u></u> | Н    | L        | _         |
| Н      | Н  | Х | 7_      | Qn   | Qn       | No Change |

### X: Don't care

# **IEC Logic Symbol**



### **Operating Ranges**

| Characteristics          | Symbol           | Rating   | Unit |  |
|--------------------------|------------------|--|------|--|
| Supply voltage           | V <sub>CC</sub>  | 1.65 to 5.5  | V    |  |
| Supply voltage           | v CC             | 1.5 to 5.5 (Note 4)  | V    |  |
| Input voltage            | V <sub>IN</sub>  | 0 to 5.5   | V    |  |
| Output voltage           | V <sub>OUT</sub> | 0 to 5.5 (Note 5)  | V    |  |
|                          |                  | 0 to V <sub>CC</sub> (Note 6)                                      | V    |  |
| Operating temperature    | T <sub>opr</sub> | -40 to 85  | °C   |  |
|                          |                  | 0 to 20 (V <sub>CC</sub> = 1.80 V $\pm$ 0.15 V, 2.5 V $\pm$ 0.2 V) |      |  |
| Input rise and fall time | dt/dv            | 0 to 10 (V <sub>CC</sub> = 3.3 V $\pm$ 0.3 V)                      | ns/V |  |
|                          |                  | 0 to 5 ( $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$ )              |      |  |

Note 4: Data retention only

Note 5:  $V_{CC} = 0 V$ 

Note 6: High or low state



### **Electrical Characteristics**

### **DC Characteristics**

| Characteristics          |   | Symbol                | Symbol Test Condition                                   |                           |                | Ta = 25°C              |      |                        | Ta = -40 to 85°C       |                        | Unit |
|--------------------------|---|-----------------------|---|---------------------------|----------------|------------------------|------|------------------------|------------------------|------------------------|------|
|                          |   | Symbol Test Condition |   | V <sub>CC</sub> (V)       | Min            | Тур.                   | Max  | Min                    | Max                    | Unit                   |      |
| Input voltage  Low leve  | High lavel  | V                     | _   |                           | 1.65 to<br>1.8 | V <sub>CC</sub> × 0.75 |      |                        | V <sub>CC</sub> × 0.75 |                        | V    |
|                          | nigirievei  | V <sub>IH</sub>       |   |                           | 2.3 to 5.5     | V <sub>CC</sub> × 0.7  | _    | _                      | V <sub>CC</sub> × 0.7  | _                      |      |
|                          | Lowlove   |                       | _   |                           | 1.65 to<br>1.8 | _                      | _    | V <sub>CC</sub> × 0.25 | _                      | V <sub>CC</sub> × 0.25 |      |
|                          | Low level   | V <sub>IL</sub>       |   |                           | 2.3 to 5.5     | _                      |      | V <sub>CC</sub> × 0.3  | _                      | V <sub>CC</sub> × 0.3  |      |
|                          |   |                       |   |                           | 1.65           | 1.55                   | 1.65 |                        | 1.55                   |                        |      |
|                          |   |                       |   | I <sub>OH</sub> = -100 μA | 2.3            | 2.2                    | 2.3  | _                      | 2.2                    |                        |      |
|                          |   |                       |   | ΙΟΗ = -100 μΑ             | 3.0            | 2.9                    | 3.0  | _                      | 2.9                    |                        |      |
|                          |   |                       |   |                           | 4.5            | 4.4                    | 4.5  | _                      | 4.4                    |                        |      |
|                          | High level  | Vон                   | V <sub>IN</sub> = V <sub>IH</sub><br>or V <sub>IL</sub> | $I_{OH} = -4 \text{ mA}$  | 1.65           | 1.29                   | 1.52 |                        | 1.29                   |                        | V    |
|                          |   |                       |   | $I_{OH} = -8 \text{ mA}$  | 2.3            | 1.9                    | 2.15 |                        | 1.9                    |                        |      |
|                          |   |                       |   | $I_{OH} = -16 \text{ mA}$ | 3.0            | 2.4                    | 2.8  |                        | 2.4                    |                        |      |
|                          |   |                       |   | $I_{OH} = -24 \text{ mA}$ | 3.0            | 2.3                    | 2.68 |                        | 2.3                    |                        |      |
| Output                   |   |                       |   | $I_{OH} = -32 \text{ mA}$ | 4.5            | 3.8                    | 4.2  |                        | 3.8                    |                        |      |
| voltage                  |   | V <sub>OL</sub>       | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>    | Ι <sub>ΟL</sub> = 100 μΑ  | 1.65           |                        | 0    | 0.1                    | _                      | 0.1                    |      |
|                          |   |                       |   |                           | 2.3            |                        | 0    | 0.1                    | _                      | 0.1                    |      |
|                          |   |                       |   |                           | 3.0            | _                      | 0    | 0.1                    | _                      | 0.1                    |      |
|                          |   |                       |   |                           | 4.5            | _                      | 0    | 0.1                    | _                      | 0.1                    |      |
|                          | Low level   |                       |   | I <sub>OL</sub> = 4 mA    | 1.65           | _                      | 0.08 | 0.24                   | _                      | 0.24                   | V    |
|                          |   |                       |   | $I_{OL} = 8 \text{ mA}$   | 2.3            | _                      | 0.1  | 0.3                    | _                      | 0.3                    |      |
|                          |   |                       |   | I <sub>OL</sub> = 16 mA   | 3.0            | _                      | 0.15 | 0.4                    | _                      | 0.4                    |      |
|                          |   |                       |   | I <sub>OL</sub> = 24 mA   | 3.0            | _                      | 0.22 | 0.55                   | _                      | 0.55                   |      |
|                          |   |                       |   | I <sub>OL</sub> = 32 mA   | 4.5            | _                      | 0.22 | 0.55                   | _                      | 0.55                   |      |
| Input leakage            | current   | I <sub>IN</sub>       | V <sub>IN</sub> = 5.5 V or GND                          |                           | 0 to 5.5       | _                      | _    | ±1                     | _                      | ±10                    | μΑ   |
| Power off lea            | Power off leakage current $I_{OFF}$ $V_{IN}$ or $V_{OUT} = 5.5 \text{ V}$ |                       | <sub>JT</sub> = 5.5 V                                   | 0.0                       | _              | _                      | 1    | _                      | 10                     | μА                     |      |
| Quiescent supply current |   | Icc                   | V <sub>IN</sub> = 5.5 V or GND                          |                           | 1.65 to<br>5.5 | _                      | _    | 1                      | _                      | 10                     | μА   |

3 2009-09-17

### AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3$ ns)

| Characteristics                                 | Symbol             | Toot Condition   | _                   | Ta = 25°C |      |      | Ta = -40 to 85°C |      | Unit  |
|---|--------------------|--|---------------------|-----------|------|------|------------------|------|-------|
| Characteristics                                 | Syllibol           | Test Condition   | V <sub>CC</sub> (V) | Min       | Тур. | Max  | Min              | Max  | Offic |
| Maximum clock frequency                         |                    | $C_L = 50 \text{ pF}, R_L = 500 \Omega$                    | $1.80\pm0.15$       | 51        | _    | _    | 38               | _    | - MHz |
|   | f <sub>MAX</sub>   |  | 2.5 ± 0.2           | 130       | _    | _    | 100              | _    |       |
| Maximum clock frequency                         | INIAX              | O <sub>L</sub> = 30 μι , ιν <sub>L</sub> = 300 Ω           | $3.3\pm0.3$         | 200       | _    | _    | 150              | _    |       |
|   |                    |  | 5.0 ± 0.5           | 200       | _    | _    | 180              | _    |       |
|   |                    |  | $1.80 \pm 0.15$     | 2.5       | 10.0 | 18.0 | 2.1              | 23.0 |       |
|   |                    | 0 45 pE D 4 MO   | 2.5 ± 0.2           | 2.0       | 4.9  | 7.5  | 1.7              | 9.0  |       |
| Propagation delay time                          | t <sub>pLH</sub>   | $C_L = 15 \text{ pF}, R_L = 1 \text{ M}\Omega$             | $3.3 \pm 0.3$       | 1.5       | 3.3  | 4.8  | 1.3              | 5.6  | ne    |
| (CK-Q, $\overline{Q}$ )                         | t <sub>pHL</sub>   |  | 5.0 ± 0.5           | 1.0       | 2.4  | 3.5  | 1.0              | 3.9  | ns    |
|   |                    | $C_L = 50 \text{ pF}, R_L = 500 \Omega$                    | $3.3 \pm 0.3$       | 2.0       | 4.3  | 5.7  | 1.5              | 7.0  |       |
|   |                    | C <sub>L</sub> = 30 μι , κ <sub>L</sub> = 300 Ω            | $5.0\pm0.5$         | 1.5       | 2.8  | 4.0  | 1.3              | 4.4  |       |
|   |                    |  | $1.80\pm0.15$       | 2.5       | 10.0 | 17.0 | 2.1              | 21.0 |       |
|   |                    | $C_L = 15 \text{ pF}, R_L = 1 \text{ M}\Omega$             | $2.5\pm0.2$         | 2.0       | 5.0  | 7.3  | 1.7              | 8.8  |       |
| Propagation delay time                          | t <sub>pLH</sub>   | C <sub>L</sub> = 13 μι , κ <sub>L</sub> = 1 Ινί <u>ς</u> 2 | $3.3 \pm 0.3$       | 1.5       | 3.4  | 4.8  | 1.3              | 5.6  | ns    |
| $(\overline{CLR},\overline{PR}-Q,\overline{Q})$ | t <sub>pHL</sub>   |  | $5.0\pm0.5$         | 1.5       | 2.2  | 3.5  | 1.0              | 3.9  | 115   |
|   |                    | $C_L = 50 \text{ pF}, R_L = 500 \Omega$                    | $3.3 \pm 0.3$       | 2.0       | 4.3  | 5.7  | 1.5              | 7.0  |       |
|   |                    |  | 5.0 ± 0.5           | 1.0       | 3.1  | 3.9  | 1.0              | 4.3  |       |
|   | ts                 | $C_L$ = 50 pF, $R_L$ = 500 $\Omega$                        | $2.5\pm0.2$         | 3.4       | _    |      | 4.1              | _    | ns    |
| Minimum setup time                              |                    |  | $3.3 \pm 0.3$       | 2.1       | _    |      | 2.5              | _    |       |
|   |                    |  | $5.0\pm0.5$         | 1.5       | _    |      | 1.7              | _    |       |
|   | t <sub>h</sub>     | $C_L = 50$ pF, $R_L = 500~\Omega$                          | $2.5\pm0.2$         | 2.4       | _    |      | 2.9              | _    | ns    |
| Minimum hold time                               |                    |  | $3.3 \pm 0.3$       | 1.4       | _    | _    | 1.5              | _    |       |
|   |                    |  | 5.0 ± 0.5           | 1.0       | _    |      | 1.1              | _    |       |
| Minimum pulse width                             | <b>4</b> (1.)      |  | $2.5 \pm 0.2$       | 3.0       | _    | _    | 3.6              | _    |       |
| (CK)  | t <sub>W</sub> (L) | $C_L = 50 \text{ pF}, R_L = 500 \Omega$                    | $3.3 \pm 0.3$       | 3.0       | _    |      | 3.3              | _    | ns    |
| (OR)  | ιW (Π)             |  | $5.0 \pm 0.5$       | 3.0       | _    | _    | 3.2              | _    |       |
| Minimum pulse width (CLR, PR)                   | t <sub>W</sub> (L) | $C_L$ = 50 pF, $R_L$ = 500 $\Omega$                        | 2.5 ± 0.2           | 3.0       | _    | _    | 3.6              | _    | ns    |
|   |                    |  | $3.3 \pm 0.3$       | 3.0       | _    | _    | 3.3              | _    |       |
| (OLIX, TIX)                                     |                    |  | 5.0 ± 0.5           | 3.0       | _    | _    | 3.2              | _    |       |
| Minimum removal time                            | t <sub>rem</sub>   | $C_L = 50$ pF, $R_L = 500 \Omega$                          | 2.5 ± 0.2           | 3.6       | _    | _    | 4.4              | _    | ns    |
|   |                    |  | 3.3 ± 0.3           | 2.2       | _    | _    | 2.5              | _    |       |
|   |                    |  | 5.0 ± 0.5           | 1.3       | _    | _    | 1.4              | _    |       |
| Input capacitance                               | C <sub>IN</sub>    | _  | 0 to 0.5            |           | 3.0  | _    | _                | _    | pF    |
| Output capacitance                              | C <sub>OUT</sub>   | _  | 0 tp 0.5            |           | 5.0  | _    | _                | _    | pF    |
| Power dissipation                               | Coo                | (Note 7)   | 3.3                 |           | 30   | _    | _                | _    | pF    |
| capacitance                                     | C <sub>PD</sub>    | (Note 7)   | 5.5                 |           | 47   | _    | _                |      | PΓ    |

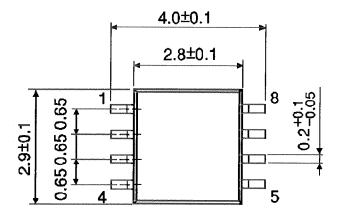
Note 7: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

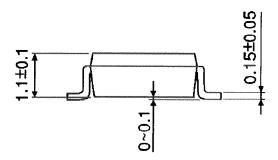
Average operating current can be obtained by the equation:

 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

### **Package Dimensions**

SSOP8-P-0.65 Unit: mm

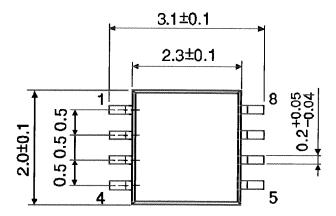


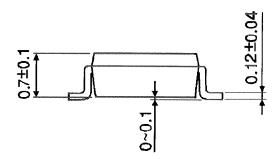


Weight: 0.02 g (typ.)

### **Package Dimensions**

SSOP8-P-0.50A Unit: mm





6

Weight: 0.01 g (typ.)

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